

SP6401

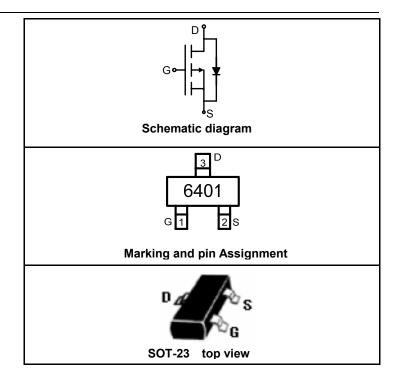
DESCRIPTION The SP6401 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as -0.4V. This device is suitable for use as a load switch or in PWM applications.

GENERAL FEATURES

- $V_{DS} = -20V, I_D = -4.3A$ $R_{DS(ON)} < 85m\Omega @ V_{GS} = -2.5V$ $R_{DS(ON)} < 50m\Omega @ V_{GS} = -4.5V$
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- •PWM applications
- Load switch
- Power management



PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
6401	SP6401	SOT-23	Ø180mm	8 mm	3000 units

ABSOLUTE MAXIMUM RATINGS(TA=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-20	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous@ Current-Pulsed (Note 1)	Ι _D	-4.3	А
Drain Current-Continuous@ Current-Fuised (Note 1)	I _{DM}	-34	А
Maximum Power Dissipation	PD	1.3	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{0JA}	100	°C/W	
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ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-20			V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-20V, V_{GS} =0V			-1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V			±100	nA

ON CHARACTERISTICS (Note 3)



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Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250µA	-0.4		-1	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-4.3A			50	mΩ
Drain-Source On-State Resistance		V _{GS} =-2.5V, I _D =-2.5A			85	
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-4.3A		7		S
DYNAMIC CHARACTERISTICS (Note4)	·					
Input Capacitance	Clss			740		PF
Output Capacitance	Coss	V _{DS} =-4V,V _{GS} =0V, F=1.0MHz		290		PF
Reverse Transfer Capacitance	C _{rss}			190		PF
SWITCHING CHARACTERISTICS (Note 4))					
Turn-on Delay Time	t _{d(on)}			27		nS
Turn-on Rise Time	tr			60		nS
Turn-Off Delay Time	t _{d(off)}	,R _{GEN} =6Ω		110		nS
Turn-Off Fall Time	t _f			80		nS
Total Gate Charge	Qg			7.8	15	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-4V,I _D =-4.3A,V _{GS} =-4.5V		1.2		nC
Gate-Drain Charge	Q _{gd}			1.6		nC
DRAIN-SOURCE DIODE CHARACTERIST	ICS		1	·I		
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-3.3A			-1.2	V
Diode Forward Current (Note 2)	Is				-1.4	А

NOTES:

Repetitive Rating: Pulse width limited by maximum junction temperature.
 Surface Mounted on FR4 Board, t ≤ 10 sec.
 Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
 Guaranteed by design, not subject to production testing.



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

Vgs Rgen G S Vout

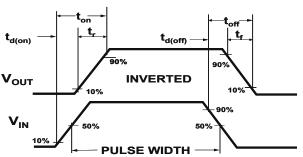


Figure 1:Switching Test Circuit

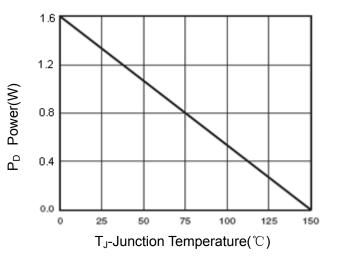


Figure 3 Power Dissipation

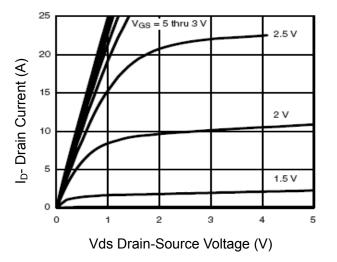
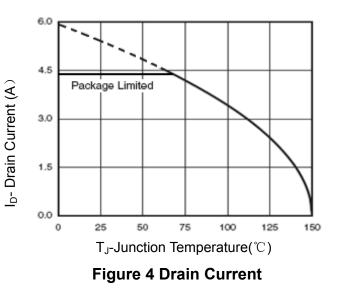


Figure 5 Output CHARACTERISTICS

Figure 2:Switching Waveforms



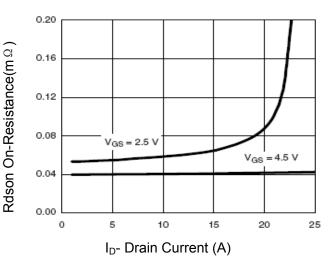
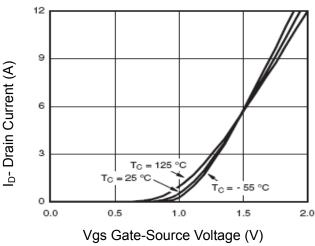


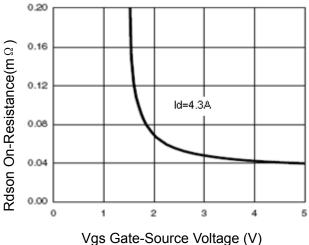
Figure 6 Drain-Source On-Resistance



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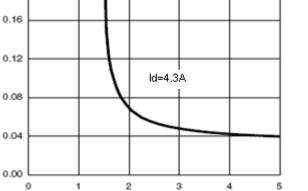


Figure 9 Rdson vs Vgs

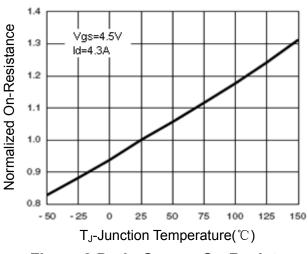


Figure 8 Drain-Source On-Resistance

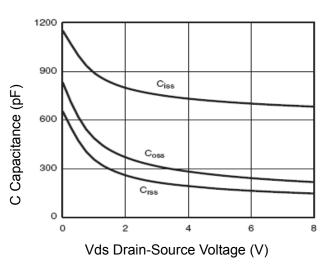
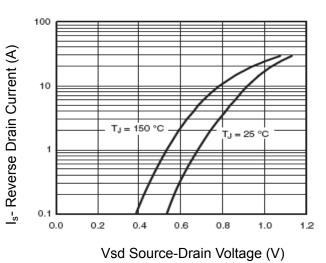


Figure 10 Capacitance vs Vds



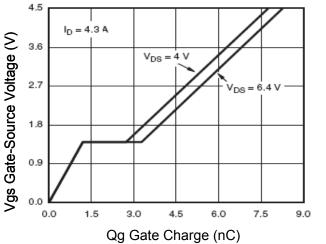




Figure 12 Source- Drain Diode Forward



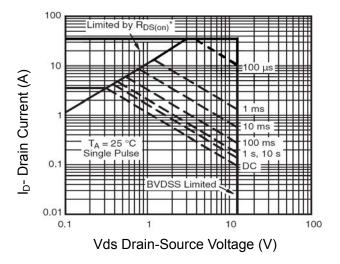


Figure 13 Safe Operation Area

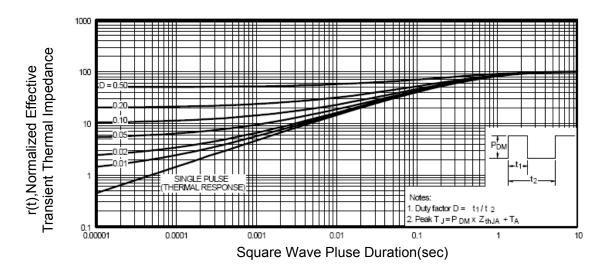
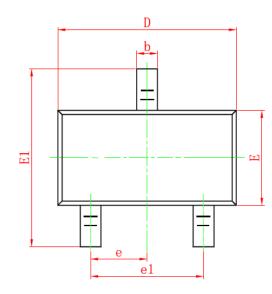
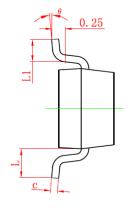


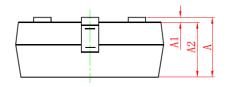
Figure 14 Normalized Maximum Transient Thermal Impedance

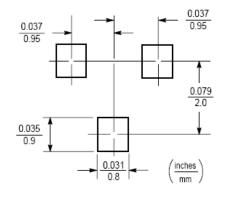


SOT-23 PACKAGE INFORMATION









Symbol	Dimensions in Millimeters			
Symbol	MIN.	MAX.		
Α	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е	0.950TYP			
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.500		
θ	0° 8°			

NOTES

- All dimensions are in millimeters.
 Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- Dimension L is measured in gauge plane.
 Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

Dimensions in Millimeters (UNIT:mm)



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